Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Metal
Overall Length:
0.780 inches
Overall Diameter:
1.900 inches
Mounting Method:
Press fit
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
5000.0 reverse voltage, peak
Current Rating Per Characteristic:
10.00 milliamperes forward current, average
Maximum Operating Tempurature Per Measurement Point:
150.0 degrees celsius ambient air
Terminal Type And Quantity:
1 threaded stud and 1 case
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0